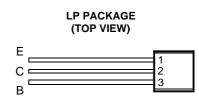
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- 20 W Pulsed Power Dissipation
- 100 V Capability
- 2 A Continuous Collector Current
- 4 A Peak Collector Current
- Customer-Specified Selections Available



MDTRAB

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

| RATING | | | VALUE | UNIT | |
|--|---------|------------------|-------------|------|--|
| | TIPP31 | | 40 | | |
| Collector-base voltage (I _E = 0) | TIPP31A | V | 60 | v | |
| | TIPP31B | V _{CBO} | 80 | | |
| | TIPP31C | | 100 | | |
| Collector-emitter voltage ($I_B = 0$) | TIPP31 | | 40 | V | |
| | TIPP31A | V | 60 | | |
| | TIPP31B | V _{CEO} | 80 | | |
| | TIPP31C | | 100 | | |
| Emitter-base voltage | | | 5 | V | |
| Continuous collector current | | | 2 | А | |
| Peak collector current (see Note 1) | | | 4 | А | |
| Continuous base current | | | 1 | А | |
| Continuous device dissipation at (or below) 25°C case temperature (see Note 2) | | | 0.8 | W | |
| Pulsed power dissipation (see Note 3) | | | 20 | W | |
| Operating junction temperature range | Тj | -55 to +150 | °C | | |
| Storage temperature range | | | -55 to +150 | °C | |
| Lead temperature 3.2 mm from case for 10 seconds | TL | 260 | °C | | |

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$

2. Derate linearly to 150°C case temperature at the rate of 6.4 mW/°C.

3. V_{CE} = 20 V, I_{C} = 1 A, t_{p} = 10 ms, duty cycle \leq 2%.





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electrical characteristics at 25°C case temperature

| | PARAMETER | | TEST CONDITI | ONS | MIN | TYP | MAX | UNIT |
|----------------------|--|--|------------------------|---------------------------|-----|-----|-----|------|
| V(DD)OFO | | $I_{\rm C} = 5 \text{ mA}$ $I_{\rm B} = 0$ (see Note 4) | TIPP31 | 40 | | | | |
| | Collector-emitter | | I _B = 0 | TIPP31A | 60 | | | V |
| | breakdown voltage | | | TIPP31B | 80 | | | |
| | | | | TIPP31C | 100 | | | |
| I _{CES} | | V _{CE} = 40 V | $V_{BE} = 0$ | TIPP31 | | | 0.2 | |
| | Collector-emitter cut-off current | V _{CE} = 60 V | $V_{BE} = 0$ | TIPP31A | | | 0.2 | mA |
| | | V _{CE} = 80 V | $V_{BE} = 0$ | TIPP31B | | | 0.2 | |
| | | V _{CE} = 100 V | $V_{BE} = 0$ | TIPP31C | | | 0.2 | |
| I _{CEO} | Collector cut-off | V _{CE} = 30 V | I _B = 0 | TIPP31/31A | | | 0.3 | mA |
| | current | V _{CE} = 60 V | I _B = 0 | TIPP31B/31C | | | 0.3 | ША |
| I _{EBO} | Emitter cut-off | V _{EB} = 5 V | I _C = 0 | | | | 1 | mA |
| | current | | | | | | | |
| h _{FE} | Forward current | $V_{CE} = 4 V$ | I _C = 1 A | (see Notes 4 and 5) | 20 | | | |
| | transfer ratio $V_{CE} = 4 V$ $I_C = 2 A$ (600 Holes 4 and 6 | (000 1000 1 414 0) | 10 | | | | | |
| V _{CE(sat)} | Collector-emitter | I _B = 375 mA | $I_{\rm C} = 2 \rm A$ | = 2 A (see Notes 4 and 5) | | | 1 | V |
| | saturation voltage | -B | | | | | | |
| V _{BE} | Base-emitter | $V_{CE} = 4 V$ | $I_{\rm C} = 2 \rm A$ | (see Notes 4 and 5) | | | 1.5 | V |
| • BE | voltage | ICE II | | | | | | |
| h _{fe} | Small signal forward | V _{CE} = 10 V | I _C = 0.5 A | f = 1 kHz | 20 | | | |
| | current transfer ratio | ·CE ·C | | | 10 | | | |
| h _{fe} | Small signal forward | V _{CE} = 10 V | I _C = 0.5 A | f = 1 MHz | 3 | | | |
| | current transfer ratio | 02 | | | - | | | |

NOTES: 4. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle \leq 2%.

5. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

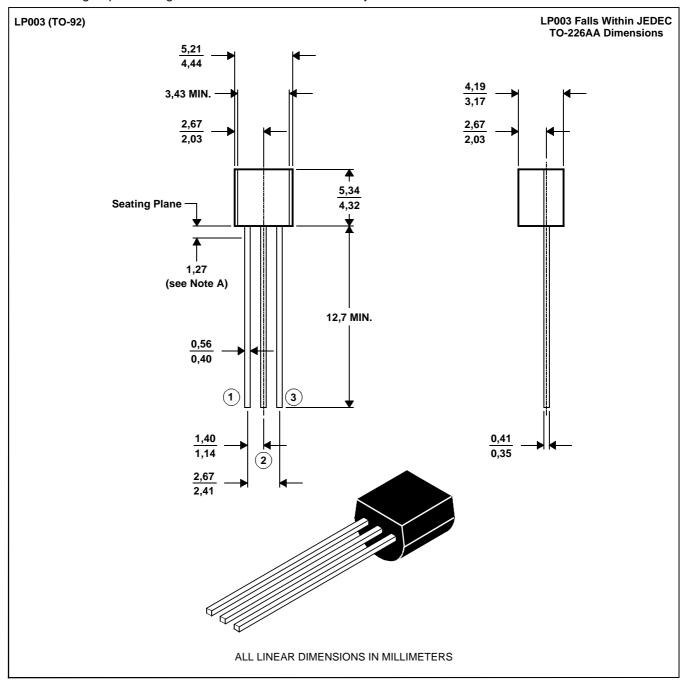
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MECHANICAL DATA

LP003 (TO-92)

3-pin cylindical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

MDXXAX



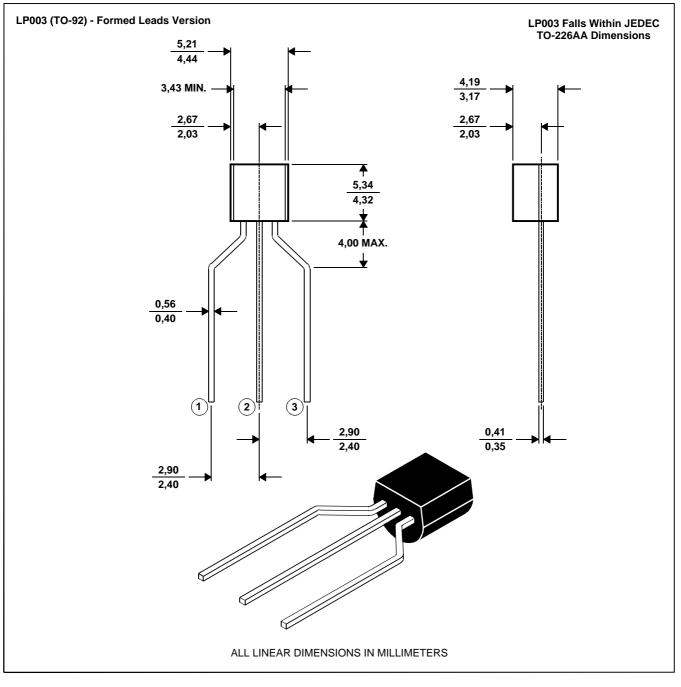
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MECHANICAL DATA

LP003 (TO-92)

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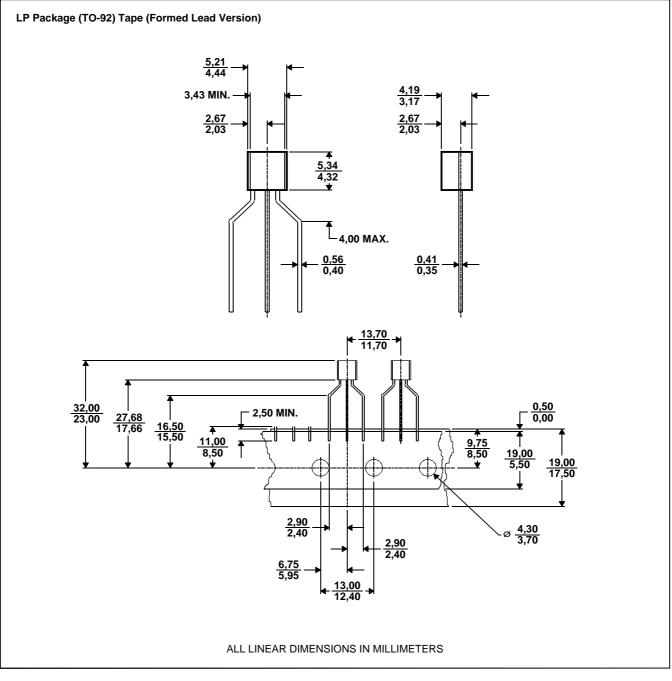


MDXXAR

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MECHANICAL DATA

LPR tape dimensions



MDXXAS



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